





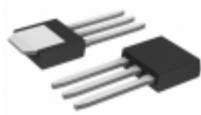
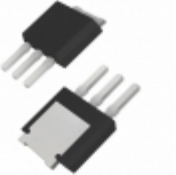
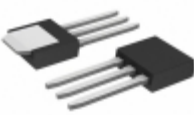

	NTD4858NT4G
	Hersteller-Teilenummer: NTD4858NT4G
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 25V 11.2A DPAK
	Datenblätter:  NTD4858NT4G.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 66767 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.	

Spezifikationen

Teilenummer	NTD4858NT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 25V 11.2A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	66767 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.3W (Ta), 54.5W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	11.2A (Ta), 73A (Tc)
Rds On (Max) @ Id, Vgs	6.2 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	19.2nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	1563pF @ 12V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































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Sie können auch interessiert sein:

 <p>NTD4860NA-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 65A IPAK TRIMMED</p>	 <p>NTD4860N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 10.4A IPAK</p>	 <p>NTD4858NAT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 11.2A DPAK</p>	 <p>NTD4860N ON/ NTD4860N ON/</p>
 <p>NTD4858NA-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 11.2A IPAK</p>	 <p>NTD4858NA-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 11.2A IPAK</p>	 <p>NTD4860NA-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 65A IPAK</p>	 <p>NTD4858NG ON NTD4858NG ON</p>

heiße Teile

Mehr

 NTD4810N	 NTD4810N-1G	 NTD4810N-35G	 NTD4810NHT4G	 NTD4810NT4G
 NTD4813N	 NTD4813N-1G	 NTD4813NH-1G	 NTD4813NH-35G	 NTD4813NHG
 NTD4813NHT4G	 NTD4813NT4G	 NTD4815N	 NTD4815N-1G	 NTD4815NHT4G
 NTD4815NT4G	 NTD4854NT4G	 NTD4855N	 NTD4855NT4G	 NTD4856NG
 NTD4856NT4G	 NTD4857NAT4G	 NTD4857NT4G	 NTD4858N	 NTD4858NAT4G
 NTD4860N	 NTD4860NA-1G	 NTD4860NAT4G	 NTD4860NT4G	 NTD4863N
 NTD4863NAT4G	 NTD4863NT4G	 NTD4865N	 NTD4904N	 NTD4904N-1G
 NTD4904N-35G	 NTD4904NT4G	 NTD4905NT4G	 NTD4906N	 NTD4906N-1G
 NTD4906N-35G	 NTD4906NAS1	 NTD4906NAT4G	 NTD4906NAT4H	 NTD4906NT4G
 NTD4906NT4H	 NTD4909N	 NTD4909N-35G	 NTD4909NAT4H	 NTD4909NT4G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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